

preliminary data

$$I_{FAVM} = 2 \times 147 \text{ A}$$

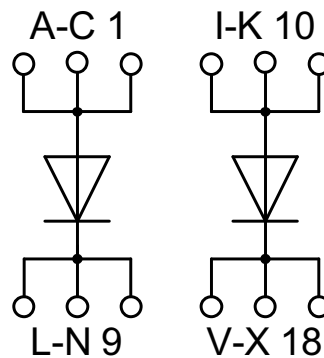
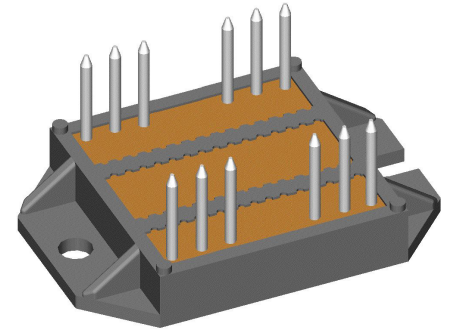
$$V_{RRM} = 600 \text{ V}$$

$$t_{rr} = 35 \text{ ns}$$

Fast Recovery Epitaxial Diode (FRED)

Part number

DSEI2x161-06P



Features / Advantages:

- 2 independent FRED in 1 package
- Planar passivated chips
- Very short recovery time
- Leads suitable for PC board soldering
- Very short recovery time
- Soft recovery behaviour
- Easy to mount with two screws
- Space and weight savings
- Improved temperature and power cycling capability
- Low noise switching
- Small and light weight

Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Package: ECO-PAC2

- Isolation voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Height: 9 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

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Diode				Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.	
I_{FRMS}	RMS forward current		$T_{VJ} = T_{VJM}$			270	A
I_{FAVM} ①	max. average forward current	rectangular, d = 0.5	$T_C = 70^{\circ}C$			147	A
I_{FSM}	max. surge forward current	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			1200	A
		t = 8.3 ms (60 Hz), sine				1300	A
		t = 10 ms (50 Hz), sine	$T_{VJ} = 150^{\circ}C$			1080	A
		t = 8.3 ms (60 Hz), sine				1170	A
I^2t	I^2t value for fusing	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			7200	A ² s
		t = 8.3 ms (60 Hz), sine				7100	A ² s
		t = 10 ms (50 Hz), sine	$T_{VJ} = 150^{\circ}C$			5800	A ² s
		t = 8.3 ms (60 Hz), sine				5700	A ² s
I_R	reverse current	$V_R = V_{RRM}$	$T_{VJ} = 25^{\circ}C$			12	mA
		$V_R = 0.8 \cdot V_{RRM}$	$T_{VJ} = 25^{\circ}C$			3	mA
		$V_R = 0.8 \cdot V_{RRM}$	$T_{VJ} = 125^{\circ}C$			80	mA
V_F	forward voltage	$I_F = 200$ A	$T_{VJ} = 25^{\circ}C$			1.45	V
V_{TO}	threshold voltage	for power-loss calculations only	$T_{VJ} = T_{VJM}$			0.85	V
r_T	slope resistance					2.7	mΩ
R_{thJC}	thermal resistance junction to case				0.20	0.29	K/W
R_{thCH}	thermal resistance junction to heatsink						K/W
I_{RM}	max. reverse recovery current	$I_F = 100$ A; $-di_F/dt = 200$ A/μs $V_R = 100$ V; $L \leq 0.05$ μH	$T_{VJ} = 100^{\circ}C$		45		A
t_{rr}	reverse recovery time	$I_F = 1$ A; $-di/dt = 400$ A/μs; $V_R = 30$ V	$T_{VJ} = 25^{\circ}C$		35		ns

① I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$, duty cycle d = 0.5

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Package	ECO-PAC2			Ratings			
Symbol	Definitions	Conditions		min.	typ.	max.	
I_{RMS}	<i>RMS current</i>	per terminal				100	A
T_{VJ}	<i>virtual junction temperature</i>			-40		150	°C
T_{op}	<i>operation temperature</i>			-40		125	°C
T_{stg}	<i>storage temperature</i>			-40		125	°C
Weight					24		g
M_D	<i>mounting torque</i>			1.4		2.0	Nm
$d_{Spp/App}$	<i>creepage distance on surface</i>	terminal to terminal		6.0			mm
$d_{Spb/Appb}$	<i>striking distance through air</i>	terminal to backside		10.0			mm
V_{ISOL}	<i>isolation voltage</i>	t = 1 second t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1\text{ mA}$	3000 2500			V V

